

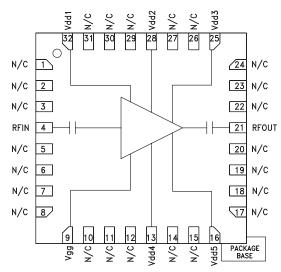


Typical Applications

The HMC489LP5 / HMC489LP5E is ideal for use as a power amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Test Equipment and Sensors
- Military End-Use

Functional Diagram



HMC489LP5 / 489LP5E

SURFACE MOUNT PHEMT 1 WATT POWER AMPLIFIER, 12 - 16 GHz

Features

Saturated Power: +32 dBm @ 16% PAE +34 dBm Output IP3 13 dB Gain +7.0 V @ 1300 mA Supply 50 Ohm Matched Input/Output 25 mm² Leadless SMT Package

General Description

The HMC489LP5 & HMC489LP5E are high dynamic range GaAs PHEMT MMIC Power Amplifiers housed in leadless 5 x 5 mm surface mount packages. Operating from 12 to 16 GHz, the amplifier provides 13 dB of gain, +32 dBm of saturated power and 16% PAE from a +7.0 V supply voltage. Output IP3 is +34 dBm typical. The RF I/Os are DC blocked and matched to 50 Ohms for ease of use. The HMC489LP5 & HMC489LP5E eliminate the need for wire bonding, allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vdd1, 2, 3, 4, 5 = +7V, Idd = 1300 mA*

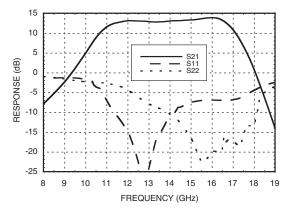
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		12 - 14		14 - 16			GHz
Gain	10	13		10	13		dB
Gain Variation Over Temperature		0.05	0.07		0.05	0.07	dB/ °C
Input Return Loss		12			8		dB
Output Return Loss		8			15		dB
Output Power for 1 dB Compression (P1dB)	24	29		28	31		dBm
Saturated Output Power (Psat)		30			32		dBm
Output Third Order Intercept (IP3)		32			34		dBm
Noise Figure		7			9		dB
Supply Current (Idd)(Vdd = +7V, Vgg = -0.3V Typ.)		1300			1300		mA

* Adjust Vgg between -2 to 0V to achieve Idd = 1300 mA typical.

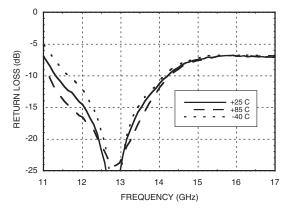




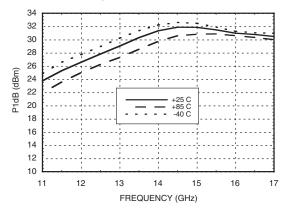
Broadband Gain and Return Loss



Input Return Loss vs. Temperature

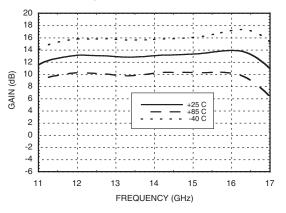


P1dB vs. Temperature

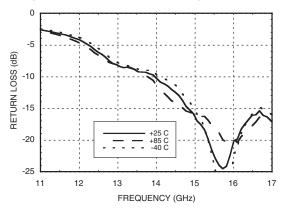


SURFACE MOUNT PHEMT 1 WATT POWER AMPLIFIER, 12 - 16 GHz

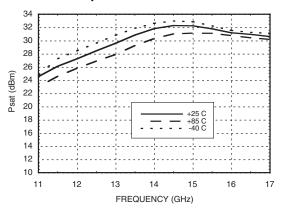
Gain vs. Temperature



Output Return Loss vs. Temperature



Psat vs. Temperature

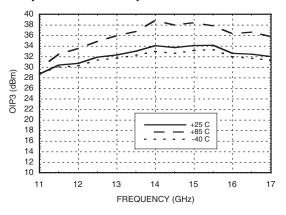


For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

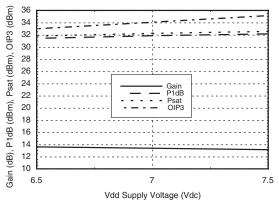




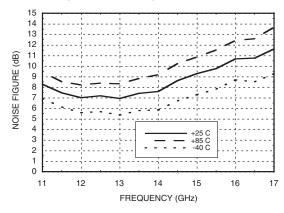
Output IP3 vs. Temperature



Gain, Power & OIP3 vs. Supply Voltage @ 15 GHz

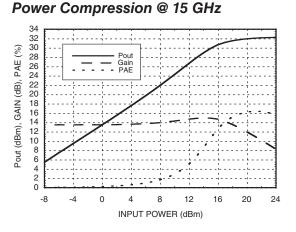


Noise Figure vs. Temperature

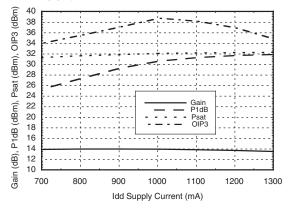


HMC489LP5 / 489LP5E

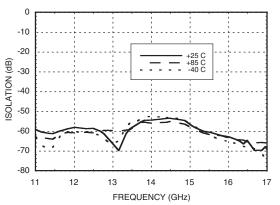
SURFACE MOUNT PHEMT 1 WATT POWER AMPLIFIER, 12 - 16 GHz



Gain, Power & OIP3 vs. Supply Current @ 15 GHz



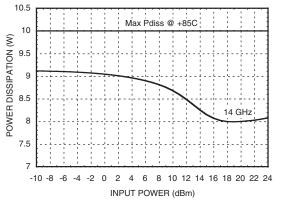
Reverse Isolation vs. Temperature







Power Dissipation*



* Refer to "Thermal Management for Surface Mount Components" application note herein.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

SURFACE MOUNT PHEMT 1 WATT POWER AMPLIFIER, 12 - 16 GHz

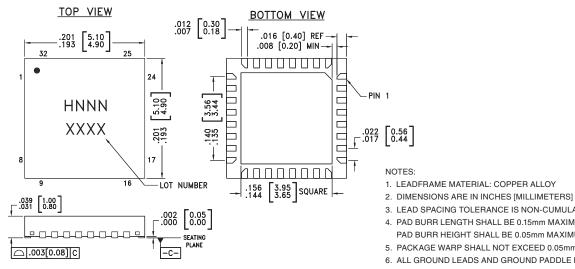
Typical Supply Current vs. Vdd

Vdd (Vdc)	ldd (mA)
+6.5	1330
+7.0	1300
+7.5	1285

Note: Amplifier will operate over full voltage ranges shown above. Vgg adjusted to achieve Idd= 1300 mA at +7.0V.

Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3, 4, 5)	+8 Vdc
Gate Bias Voltage (Vgg)	-2.0 to 0 Vdc
RF Input Power (RFin)(Vdd = +7.0 Vdc)	+28 dBm
Channel Temperature	150 °C
Continuous Pdiss (T= 85 °C) (derate 154 mW/°C above 85 °C)	10 W
Thermal Resistance (channel to ground paddle)	6.5 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM. 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]	
HMC489LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H489 XXXX	
HMC489LP5E	HMC489LP5E RoHS-compliant Low Stress Injection Molded Plastic		MSL1 ^[2]	<u>H489</u> XXXX	

[1] Max peak reflow temperature of 235 °C

Package Information

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



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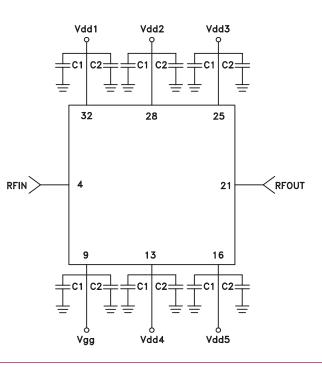


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1-3, 5-8, 10-12, 14, 15, 17-20, 22-24, 26, 27, 29-31	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms from 12 - 16 GHz.	
9	Vgg	Gate control for amplifier. Adjust to achieve Idd of 1300 mA. Please follow "MMIC Amplifier Biasing Procedure" Application Note. External bypass capacitors of 100 pF and 2.2 µF are required.	Vgg
21	RFOUT	This pin is AC coupled and matched to 50 Ohms from 12 - 16 GHz.	
32, 28, 25, 13, 16	Vdd3 Vdd4		OVdd1,2,3,4,5
	GND	Ground: Backside of package has exposed metal ground slug that must be connected to ground through a short path. Vias under the device are required	GND =

Application Circuit

Component	Value
C1	100 pF
C2	2.2 µF



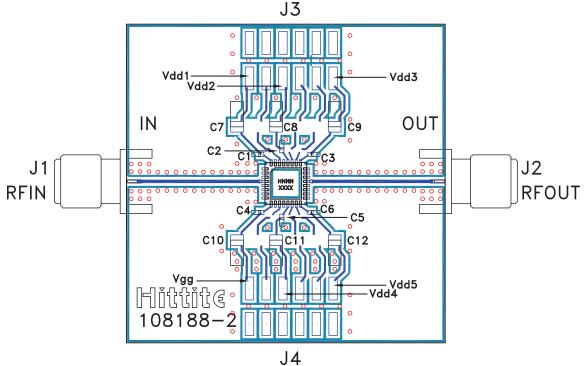


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Evaluation PCB



List of Materials for Evaluation PCB 108190 [1]

Item	Description
J1, J2	SRI PC Mount SMA Connector
J3, J4	2mm DC Header
C1 - C6	100 pF capacitor, 0402 pkg.
C7 - C12	2.2µF Capacitor, Tantalum
U1	HMC489LP5 / HMC489LP5E Amplifier
PCB [2]	108188 Evaluation PCB

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350.

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. Copper filled vias under the device are recommended. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.